# 2SC5902

## Silicon NPN triple diffusion mesa type

### Horizontal deflection output for TV

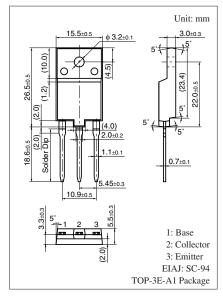
#### ■ Features

- High breakdown voltage:  $V_{CBO} \ge 1700 \text{ V}$
- Wide safe operation area
- Built-in dumper diode

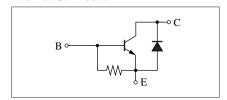
## ■ Absolute Maximum Ratings $T_C = 25$ °C

| Parameter                             | Symbol             | Rating      | Unit |  |
|---------------------------------------|--------------------|-------------|------|--|
| Collector-base voltage (Emitter open  | ) V <sub>CBO</sub> | 1700        | V    |  |
| Collector-emitter voltage (E-B short) | V <sub>CES</sub>   | 1 700       | V    |  |
| Emitter-base voltage (Collector open  | ) V <sub>EBO</sub> | 7           | V    |  |
| Base current                          | $I_{\mathrm{B}}$   | 3           | A    |  |
| Collector current                     | $I_{C}$            | 9           | A    |  |
| Peak collector current *              | $I_{CP}$           | 14          | A    |  |
| Collector power dissipation           | P <sub>C</sub>     | 40          | W    |  |
| $T_a = 25^{\circ}C$                   |                    | 3           |      |  |
| Junction temperature                  | T <sub>j</sub>     | 150         | °C   |  |
| Storage temperature                   | T <sub>stg</sub>   | -55 to +150 | °C   |  |

Note) \*: Non-repetitive peak collector current



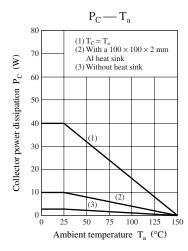
#### Internal Connection

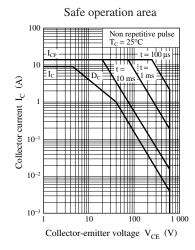


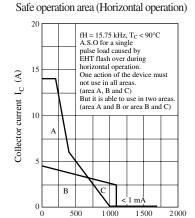
### ■ Electrical Characteristics $T_C = 25$ ° $C \pm 3$ °C

| Parameter                                    | Symbol               | Conditions  | Min | Тур | Max | Unit |
|--|----------------------|---|-----|-----|-----|------|
| Emitter-base voltage (Collector open)        | $V_{EBO}$            | $I_E = 500 \text{ mA}, I_C = 0$                                     | 7   |     |     | V    |
| Forward voltage                              | $V_F$                | I <sub>F</sub> = 4.5 A  |     |     | -2  | V    |
| Collector-base cutoff current (Emitter open) | $I_{CBO}$            | $V_{CB} = 1000 \text{ V}, I_{E} = 0$                                |     |     | 50  | μΑ   |
|  |                      | $V_{CB} = 1700 \text{ V}, I_E = 0$                                  |     |     | 1   | mA   |
| Forward current transfer ratio               | h <sub>FE</sub>      | $V_{CE} = 5 \text{ V}, I_{C} = 4.5 \text{ A}$                       | 5   |     | 10  | _    |
| Collector-emitter saturation voltage         | V <sub>CE(sat)</sub> | $I_C = 4.5 \text{ A}, I_B = 1.13 \text{ A}$                         |     |     | 3   | V    |
| Base-emitter saturation voltage              | V <sub>BE(sat)</sub> | $I_C = 4.5 \text{ A}, I_B = 1.13 \text{ A}$                         |     |     | 1.5 | V    |
| Transition frequency                         | $f_T$                | $V_{CE} = 10 \text{ V}, I_{C} = 0.1 \text{ A}, f = 0.5 \text{ MHz}$ |     | 3   |     | MHz  |
| Storage time                                 | t <sub>stg</sub>     | $I_C = 4.5 \text{ A}$ , Resistance loaded                           |     |     | 5.0 | μs   |
| Fall time                                    | t <sub>f</sub>       | $I_{B1} = 1.13 \text{ A}, I_{B2} = -2.25 \text{ A}$                 |     |     | 0.5 | μs   |

Note) Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.







Collector-emitter voltage  $V_{CE}$  (V)

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